NSN 5961-00-857-8559

Transistor - Page 1 of 1

A110a0



View Online at https://aerobasegroup.com/nsn/5961-00-857-8559 **Inclosure Material:** Metal **Overall Length:** 0.210 inches **Overall Diameter:** 0.230 inches **Internal Configuration:** Field effect Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-72 **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 30.0 drain to source voltage and 30.0 drain to gate voltage and 30.0 gate to source voltage **Current Rating Per Characteristic:** 10.00 milliamperes forward current, peak total value **Power Rating Per Characteristic:** 300.0 milliwatts total device dissipation **Test Data Document:** 94853-30196 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 4 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: